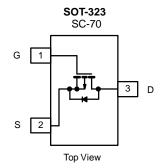


# BSS84PW-VB Datasheet P-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY						
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	V <sub>GS(th)</sub> (V)	I <sub>D</sub> (mA)			
- 60	4 at V <sub>GS</sub> = - 10 V	- 1 to - 3	- 135			



#### **FEATURES**

- Halogen-free According to IEC 61249-2-21 Definition
- Trench Power MOSFET
- High-Side Switching
- Low On-Resistance: 4 Ω
- Low Threshold: 2 V (typ.)
- Fast Swtiching Speed: 20 ns (typ.)
- Low Input Capacitance: 20 pF (typ.)
- Compliant to RoHS Directive 2002/95/EC



#### **APPLICATIONS**

- Drivers: Relays, Solenoids, Lamps, Hammers, Display, Memories, Transistors, etc.
- Battery Operated Systems
- Power Supply Converter Circuits
- · Solid-State Relays

#### **BENEFITS**

- · Ease in Driving Switches
- · Low Offset (Error) Voltage
- Low-Voltage Operation
- High-Speed Circuits
- · Easily Driven without Buffer

ABSOLUTE MAXIMUM RATINGS T <sub>A</sub> = 25 °C, unless otherwise noted						
Parameter	Symbol	Limit	Unit			
Drain-Source Voltage		V <sub>DS</sub>	- 60	V		
Gate-Source Voltage		V <sub>GS</sub>	± 20	V		
Continuous Dusin Comments	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	- 135	mA		
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> = 100 °C		- 105			
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	- 800			
Daving Dissingtion 8	T <sub>A</sub> = 25 °C	- P <sub>D</sub>	350	mW		
Power Dissipation <sup>a</sup>	T <sub>A</sub> = 100 °C		140			
Maximum Junction-to-Ambient <sup>a</sup>		R <sub>thJA</sub>	350	°C/W		
Operating Junction and Storage Temperature Range		T <sub>J,</sub> T <sub>stg</sub>	- 55 to 150	°C		

#### Notes

- a. Surface mounted on FR4 board.
- b. Pulse width limited by maximum junction temperature.

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_			Limits				
Parameter	Symbol	Test Conditions	Min.	Typ. <sup>a</sup>	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 \text{ V, } I_D = -10  \mu\text{A}$ - 60				V	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1		- 3	v	
Gate-Body Leakage		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 10	μΑ	
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}$			± 200	nA	
	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}, T_{J} = 85 \text{ °C}$			± 500		
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 5 \text{ V}$			± 100		
Zero Gate Voltage Drain Current	1	V <sub>DS</sub> = - 60 V, V <sub>GS</sub> = 0 V	- 2		- 25		
	I <sub>DSS</sub>	V <sub>DS</sub> = - 60 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 85 °C	V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 85 °C		- 250	1	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = - 10 V, V <sub>DS</sub> = - 4.5 V	- 50			^	
		V <sub>GS</sub> = - 10 V, V <sub>DS</sub> = - 10 V	- 600			— mA	
Drain-Source On-Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 25 mA	5				
		V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 100 mA		4		Ω	
		V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 100 mA, T <sub>J</sub> =125 °C			9		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 10 V, I <sub>D</sub> = - 100 mA	80			mS	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> = - 100 mA, V <sub>GS</sub> = 0 V			- 1.4	V	
Dynamic							
Total Gate Charge	Qg			1.7		nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -30 \text{ V}, V_{GS} = -15 \text{ V}$ $I_{D} \cong -100 \text{ mA}$		0.26			
Gate-Drain Charge	Q <sub>gd</sub>	10 - 100 11/10		0.46			
Input Capacitance	C <sub>iss</sub>			23		pF	
Output Capacitance	C <sub>oss</sub>	$V_{DS} = -25 \text{ V}, V_{GS} = 0 \text{ V}$ f = 1 MHz		10			
Reverse Transfer Capacitance	C <sub>rss</sub>	1 - 1 Will 12		5			
Switching <sup>b</sup>							
Turn-On Time	t <sub>d(on)</sub>	$V_{DD} = -25 \text{ V}, R_{L} = 150 \Omega$		20		ns	
Turn-Off Time	t <sub>d(off)</sub>	$I_D \cong -200 \text{ mA}, V_{GEN} = -10 \text{ V}, R_g = 10 \Omega$		35			

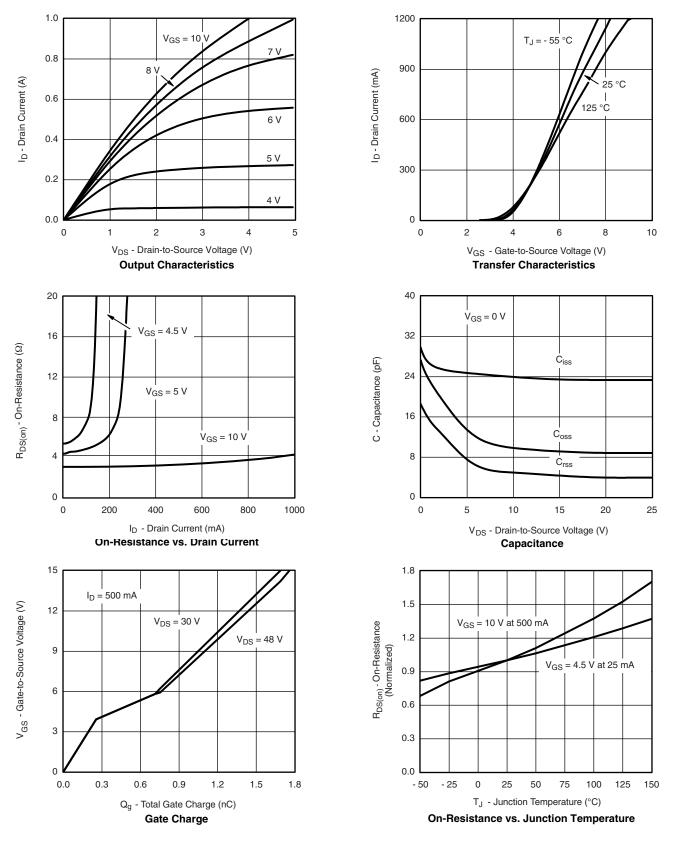
#### Notes:

- a. Pulse test: PW  $\leq 300~\mu s$  duty cycle  $\leq 2~\%.$
- b. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

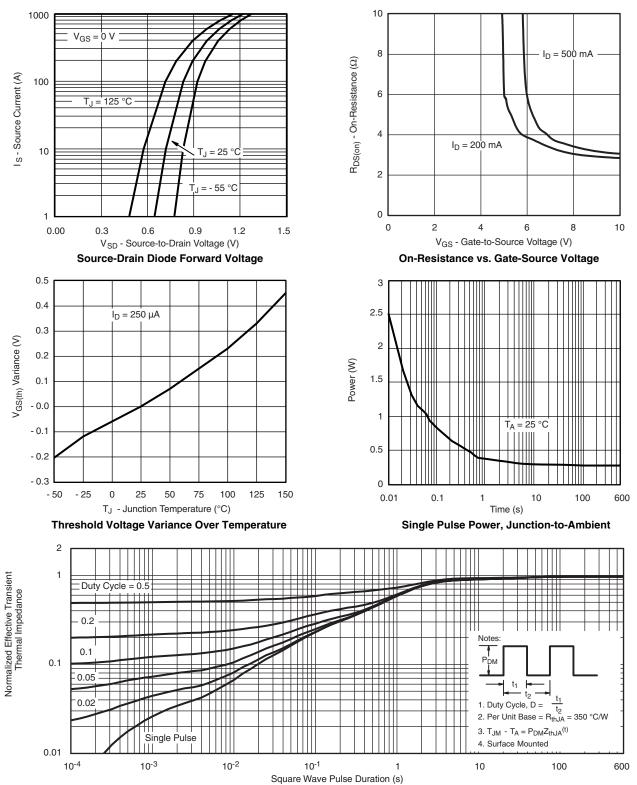


#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

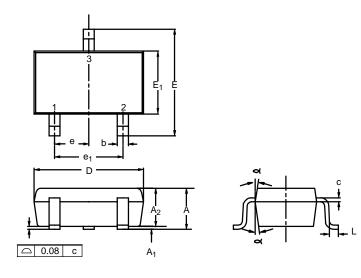


4 服务热线:400-655-8788

Normalized Thermal Transient Impedance, Junction-to-Ambient



## **SC-70: 3-LEADS**

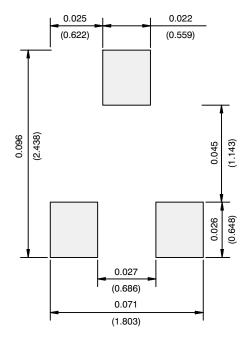


	MILLIMETERS			INCHES		
Min	Nom	Max	Min	Nom	Max	
0.90	_	1.10	0.035	_	0.043	
_	ı	0.10	-	ı	0.004	
0.80	-	1.00	0.031	_	0.039	
0.25	-	0.40	0.010	_	0.016	
0.10	ı	0.25	0.004	1	0.010	
1.80	2.00	2.20	0.071	0.079	0.087	
1.80	2.10	2.40	0.071	0.083	0.094	
1.15	1.25	1.35	0.045	0.049	0.053	
0.65BSC		0.026BSC				
1.20	1.30	1.40	0.047	0.051	0.055	
0.10	0.20	0.30	0.004	0.008	0.012	
7°Nom 7°Nom						
	0.90 - 0.80 0.25 0.10 1.80 1.15	0.90	0.90 - 1.10  0.10  0.80 - 1.00  0.25 - 0.40  0.10 - 0.25  1.80 2.00 2.20  1.80 2.10 2.40  1.15 1.25 1.35  0.65BSC  1.20 1.30 1.40  0.10 0.20 0.30  7°Nom	0.90         -         1.10         0.035           -         -         0.10         -           0.80         -         1.00         0.031           0.25         -         0.40         0.010           0.10         -         0.25         0.004           1.80         2.00         2.20         0.071           1.80         2.10         2.40         0.071           1.15         1.25         1.35         0.045           0.65BSC           1.20         1.30         1.40         0.047           0.10         0.20         0.30         0.004	0.90         -         1.10         0.035         -           -         -         0.10         -         -           0.80         -         1.00         0.031         -           0.25         -         0.40         0.010         -           0.10         -         0.25         0.004         -           1.80         2.00         2.20         0.071         0.079           1.80         2.10         2.40         0.071         0.083           1.15         1.25         1.35         0.045         0.049           0.65BSC         0.026BSC           1.20         1.30         1.40         0.047         0.051           0.10         0.20         0.30         0.004         0.008           7°Nom         7°Nom         7°Nom	

ECN: S-03946—Rev. C, 09-Jul-01 DWG: 5549



## **RECOMMENDED MINIMUM PADS FOR SC-70: 3-Lead**



Recommended Minimum Pads Dimensions in Inches/(mm)



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